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# DS90LV031AQML 3V LVDS Quad CMOS Differential Line Driver

Check for Samples: DS90LV031AQML

# **FEATURES**

- High impedance LVDS outputs with power-off
- · Low differential skew
- Low propagation delay
- 3.3V power supply design
- ±350 mV differential signaling
- Low power dissipation
- Interoperable with existing 5V LVDS devices
- Compatible with IEEE 1596.3 SCI LVDS standard
- Compatible with proposed TIA/EIA-644 LVDS standard
- Pin compatible with DS26C31
- Typical Rise/Fall times of 800pS.
- Typical Tri-State Enable/Disable delays of less than 5nS.

### DESCRIPTION

The DS90LV031A is a quad CMOS differential line driver designed for applications requiring ultra low power dissipation and high data rates. The device is designed to support data rates in excess of 400 Mbps (200 MHz) utilizing Low Voltage Differential Signaling (LVDS) technology.

The DS90LV031A accepts low voltage TTL/CMOS input levels and translates them to low voltage (350 mV) differential output signals. In addition the driver supports a TRI-STATE® function that may be used to disable the output stage, disabling the load current, and thus dropping the device to an ultra low idle power state of 13 mW typical.

The EN and EN\* inputs allow active Low or active High control of the TRI-STATE outputs. The enables are common to all four drivers. The DS90LV031A and companion line receiver (DS90LV032A) provide a new alternative to high power psuedo-ECL devices for high speed point-to-point interface applications.

# **Connection Diagram**

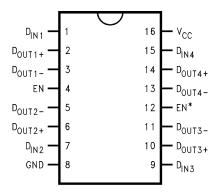


Figure 1. Dual-In-Line See Package Number NAC0016A or NAD0016A

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TRI-STATE is a registered trademark of Texas Instruments. All other trademarks are the property of their respective owners.



# **Functional Diagram**

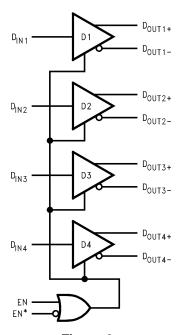


Figure 2.

# **Truth Table - Driver**

Enables	1	Input	Outputs		
En En*		D <sub>I</sub>	D <sub>O+</sub>	D <sub>O</sub> -	
L	Н	X	Z	Z	
All ather and in ations of	ENADLE innerto	L	L	Н	
All other combinations of	ENABLE Inputs	Н	Н	L	



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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# Absolute Maximum Ratings (1)

Supply Voltage (V <sub>CC</sub> )	-0.3V to +4V
Input Voltage (D <sub>I</sub> )	-0.3V to (V <sub>CC</sub> + 0.3V)
Enable Input Voltage (En, En*)	-0.3V to (V <sub>CC</sub> + 0.3V)
Output Voltage (D <sub>O</sub> +, D <sub>O</sub> -)	-0.3V to +3.9V
Storage Temperature Range	-65°C ≤ T <sub>A</sub> ≤ +150°C
Lead Temperature Range (Soldering 4 sec.)	+260°C
Maximum Junction Temperature	+150°C
Maximum Power Dissipation @ +25°C (2)	·
16LD CLGA (NAC and NAD)	845mW
Thermal Resistance	
$\theta_{JA}$	
16LD CLGA (NAC and NAD)	148°C/W
$\theta_{JC}$	·
16LD CLGA (NAC and NAD)	22°C/W
ESD Rating (3)	6KV

<sup>(1)</sup> Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

# **Recommended Operating Conditions**

	Min	Тур	Max
Supply Voltage (V <sub>CC</sub> )	+3.0V	+3.3V	+3.6V
Operating Free Air Temperature (T <sub>A</sub> )	-55°C	+25°C	+125°C

Table 1. Quality Conformance InspectionMil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp °C
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55
12	Settling time at	+25
13	Settling time at	+125
14	Settling time at	-55

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<sup>(2)</sup> Derate (NAD & NAC packages) at 6.8mW/°C for temperatures above +25°C.

<sup>(3)</sup> Human body model, 1.5 kΩ in series with 100 pF



#### **DS90LV031A Electrical Characteristics DC Parameters**

The following conditions apply, unless otherwise specified.

DC:  $V_{CC} = 3.0/3.6V$ 

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub- groups
V <sub>OD1</sub>	Differential Ouput Voltage	$R_L = 100\Omega$	Figure 3	250	450	mV	1, 2, 3
$\Delta V_{OD1}$	Δ in magnitude of V <sub>OD1</sub> for complementary output States	$R_L = 100\Omega$	Figure 3		50	mV	1, 2, 3
Vos	Offset Voltage	$R_L = 100\Omega$	Figure 3	1.125	1.625	V	1, 2, 3
ΔV <sub>OS</sub>	Δ in Magnitude of V <sub>OS</sub> for Complementary Output States	$R_L = 100\Omega$	Figure 3		50	mV	1, 2, 3
V <sub>OH</sub>	Output Voltage High	$R_L = 100\Omega$	Figure 3		1.85	V	1, 2, 3
V <sub>OL</sub>	Output Voltage Low	$R_L = 100\Omega$	Figure 3	0.9		V	1, 2, 3
V <sub>IH</sub>	Input Voltage High		(1)	2.0	V <sub>CC</sub>	V	1, 2, 3
V <sub>IL</sub>	Input Voltage Low		(1)	Gnd	0.8	V	1, 2, 3
I <sub>IH</sub>	Input Current	$V_{I} = V_{CC}$ or 2.5V, $V_{CC} = 3.6V$			±10	μA	1, 2, 3
I <sub>IL</sub>	Input Current	$V_I$ = Gnd or 0.4V, $V_{CC}$ = 3.6V			±10	μA	1, 2, 3
$V_{CI}$	Input Clamp Voltage	$I_{Cl} = -8mA, V_{CC} = 3.0V$			-1.5	V	1, 2, 3
l <sub>OS</sub>	Output Short Circuit Current	Enabled, $D_I = V_{CC}$ , $D_O+=0V$ or $D_I = Gnd$ , $D_O-=0V$		-9.0		mA	1, 2, 3
I <sub>Off</sub>	Power-off Leakage	$V_O = 0V \text{ or } 3.6V$ $V_{CC} = 0V \text{ or } V_{CC} = \text{Open}$			±20	μΑ	1, 2, 3
l <sub>OZ</sub>	Output TRI-STATE Current	En = 0.8V and En* = 2.0V V <sub>O</sub> = 0V or V <sub>CC</sub> , V <sub>CC</sub> = 3.6V			±10	μΑ	1, 2, 3
I <sub>CC</sub>	No Load Drivers Enabled Supply Current	D <sub>I</sub> = V <sub>CC</sub> or Gnd			18	mA	1, 2, 3
I <sub>CCL</sub>	Loaded Drivers Enabled Supply Current	$R_L = 100\Omega$ All Channels, $D_I = V_{CC}$ or Gnd (all inputs)			35	mA	1, 2, 3
I <sub>CCZ</sub>	Loaded or No Load Drivers Disabled Supply Current	$D_I = V_{CC}$ or Gnd, En = Gnd, En* = $V_{CC}$			12	mA	1, 2, 3

<sup>(1)</sup> Tested during  $V_{OH}/V_{OL}$  tests.

# **DS90LV031A Electrical Characteristics AC Parameters**

The following conditions apply, unless otherwise specified.

AC:  $V_{CC} = 3.0/3.3/3.6V$ ,  $R_L = 100\Omega$ ,  $C_L = 20pF$ .

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub- groups
t <sub>PHLD</sub>	Differential Propagation Delay High to Low		Figure 4 and Figure 5	0.3	3.5	ns	9, 10, 11
t <sub>PLHD</sub>	Differential Propagation Delay Low to High		Figure 4 and Figure 5	0.3	3.5	ns	9, 10, 11
t <sub>SkD</sub>	Differential Skew t <sub>PHLD</sub> - t <sub>PLHD</sub>				1.5	ns	9, 10, 11
t <sub>Sk1</sub>	Channel to Channel Skew		(1)		1.75	ns	9, 10, 11
t <sub>Sk2</sub>	Chip to Chip Skew		(2)		3.2	ns	9, 10, 11

<sup>(1)</sup> Channel to Channel Skew is defined as the difference between the propagation delay of one channel and that of the others on the same chip with any event on the inputs.

<sup>(2)</sup> Chip to Chip Skew is defined as the difference between the minimum and maximum specified differential propagation delays.



# PARAMETER MEASUREMENT INFORMATION

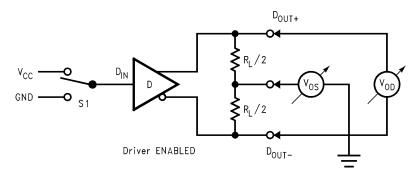


Figure 3. Driver  $V_{\text{OD}}$  and  $V_{\text{OS}}$  Test Circuit

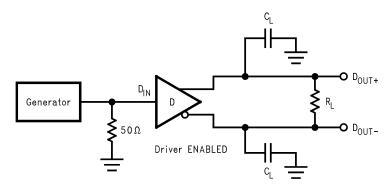


Figure 4. Driver Propagation Delay and Transition Time Test Circuit

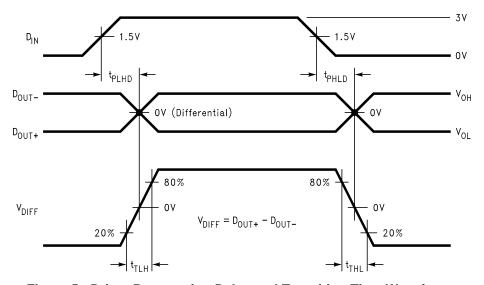


Figure 5. Driver Propagation Delay and Transition Time Waveforms



#### TYPICAL APPLICATION

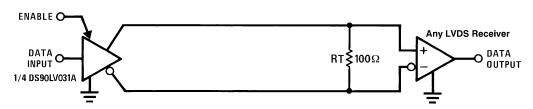


Figure 6. Point-to-Point Application

#### APPLICATION INFORMATION

General application guidelines and hints for LVDS drivers and receivers may be found in the LVDS Owner's Manual at http://www.ti.com/ww/en/analog/interface/lvds.shtml.

LVDS drivers and receivers are intended to be primarily used in an uncomplicated point-to-point configuration as is shown in Figure 6. This configuration provides a clean signaling environment for the quick edge rates of the drivers. The receiver is connected to the driver through a balanced media which may be a standard twisted pair cable, a parallel pair cable, or simply PCB traces. Typically, the characteristic differential impedance of the media is in the range of  $100\Omega$ . A termination resistor of  $100\Omega$  should be selected to match the media, and is located as close to the receiver input pins as possible. The termination resistor converts the current sourced by the driver into a voltage that is detected by the receiver. Other configurations are possible such as a multi-receiver configuration, but the effects of a mid-stream connector(s), cable stub(s), and other impedance discontinuities as well as ground shifting, noise margin limits, and total termination loading must be taken into account.

The DS90LV031A differential line driver is a balanced current source design. A current mode driver, generally speaking has a high output impedance and supplies a constant current for a range of loads (a voltage mode driver on the other hand supplies a constant voltage for a range of loads). Current is switched through the load in one direction to produce a logic state and in the other direction to produce the other logic state. The output current is typically 3.5 mA, a minimum of 2.5 mA, and a maximum of 4.5 mA. The current mode **requires** (as discussed above) that a resistive termination be employed to terminate the signal and to complete the loop as shown in Figure 6. AC or unterminated configurations are not allowed. The 3.5 mA loop current will develop a differential voltage of 350 mV across the  $100\Omega$  termination resistor which the receiver detects with a 250 mV minimum differential noise margin neglecting resistive line losses (driven signal minus receiver threshold (350 mV - 100 mV = 250 mV)). The signal is centered around +1.2V (Driver Offset,  $V_{OS}$ ) with respect to ground as shown in Figure 7. Note that the steady-state voltage ( $V_{SS}$ ) peak-to-peak swing is twice the differential voltage ( $V_{OD}$ ) and is typically 700 mV.

The current mode driver provides substantial benefits over voltage mode drivers, such as an RS-422 driver. Its quiescent current remains relatively flat versus switching frequency. Whereas the RS-422 voltage mode driver increases exponentially in most case between 20 MHz–50 MHz. This is due to the overlap current that flows between the rails of the device when the internal gates switch. Whereas the current mode driver switches a fixed current between its output without any substantial overlap current. This is similar to some ECL and PECL devices, but without the heavy static  $I_{CC}$  requirements of the ECL/PECL designs. LVDS requires > 80% less current than similar PECL devices. AC specifications for the driver are a tenfold improvement over other existing RS-422 drivers.

The TRI-STATE function allows the driver outputs to be disabled, thus obtaining an even lower power state when the transmission of data is not required.

The footprint of the DS90LV031A is the same as the industry standard 26LS31 Quad Differential (RS-422) Driver and is a step down replacement for the 5V DS90C031 Quad Driver.

# **Power Decoupling Recommendations**

Bypass capacitors must be used on power pins. High frequency ceramic (surface mount is recommended)  $0.1\mu F$  in parallel with  $0.01\mu F$ , in parallel with  $0.001\mu F$  at the power supply pin as well as scattered capacitors over the printed circuit board. Multiple vias should be used to connect the decoupling capacitors to the power planes. A  $10\mu F$  (35V) or greater solid tantalum capacitor should be connected at the power entry point on the printed circuit board.

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#### PC Board considerations

Use at least 4 PCB layers (top to bottom); LVDS signals, ground, power, TTL signals.

Isolate TTL signals from LVDS signals, otherwise the TTL may couple onto the LVDS lines. It is best to put TTL and LVDS signals on different layers which are isolated by a power/ground plane(s).

Keep drivers and receivers as close to the (LVDS port side) connectors as possible.

#### **Differential Traces**

Use controlled impedance traces which match the differential impedance of your transmission medium (ie. cable) and termination resistor. Run the differential pair trace lines as close together as possible as soon as they leave the IC (stubs should be < 10mm long). This will help eliminate reflections and ensure noise is coupled as common-mode. Lab experiments show that differential signals which are 1mm apart radiate far less noise than traces 3mm apart since magnetic field cancellation is greater with the closer traces. Plus, noise induced on the differential lines is much more likely to appear as common-mode which is rejected by the receiver.

Match electrical lengths between traces to reduce skew. Skew between the signals of a pair means a phase difference between signals which destroys the magnetic field cancellation benefits of differential signals and EMI will result. (Note the velocity of propagation, v = c/Er where c (the speed of light) = 0.2997mm/ps or 0.0118 in/ps). Do not rely solely on the auto-route function for differential traces. Carefully review dimensions to match differential impedance and provide isolation for the differential lines. Minimize the number of vias and other discontinuities on the line.

Avoid 90° turns (these cause impedance discontinuities). Use arcs or 45° bevels.

Within a pair of traces, the distance between the two traces should be minimized to maintain common-mode rejection of the receivers. On the printed circuit board, this distance should remain constant to avoid discontinuities in differential impedance. Minor violations at connection points are allowable.

#### **Termination**

Use a resistor which best matches the differential impedance of your transmission line. The resistor should be between  $90\Omega$  and  $130\Omega$ . Remember that the current mode outputs need the termination resistor to generate the differential voltage. LVDS will not work without resistor termination. Typically, connect a single resistor across the pair at the receiver end.

Surface mount 1% to 2% resistors are best. PCB stubs, component lead, and the distance from the termination to the receiver inputs should be minimized. The distance between the termination resistor and the receiver should be < 10mm (12mm MAX).

#### **Probing LVDS Transmission Lines**

Always use high impedance (>  $100k\Omega$ ), low capacitance (< 2pF) scope probes with a wide bandwidth (1GHz) scope. Improper probing will give deceiving results.

# **Cables and Connectors, General Comments**

When choosing cable and connectors for LVDS it is important to remember:

Use controlled impedance media. The cables and connectors you use should have a matched differential impedance of about  $100\Omega$ . They should not introduce major impedance discontinuities.

Balanced cables (e.g. twisted pair) are usually better than unbalanced cables (ribbon cable, simple coax.) for noise reduction and signal quality. Balanced cables tend to generate less EMI due to field canceling effects and also tend to pick up electromagnetic radiation a common-mode (not differential mode) noise which is rejected by the receiver. For cable distances < 0.5M, most cables can be made to work effectively. For distances 0.5M  $\leq$  d  $\leq$  10M, CAT 3 (category 3) twisted pair cable works well, is readily available and relatively inexpensive.

# Fail-safe Feature

The LVDS receiver is a high gain, high speed device that amplifies a small differential signal (20mV) to CMOS logic levels. Due to the high gain and tight threshold of the receiver, care should be taken to prevent noise from appearing as a valid signal.



The receiver's internal fail-safe circuitry is designed to source/sink a small amount of current, providing fail-safe protection (a stable known state of HIGH output voltage) for floating, terminated or shorted receiver inputs.

- 1. **Open Input Pins.** The DS90LV032A is a quad receiver device, and if an application requires only 1, 2 or 3 receivers, the unused channel(s) inputs should be left OPEN. Do not tie unused receiver inputs to ground or any other voltages. The input is biased by internal high value pull up and pull down resistors to set the output to a HIGH state. This internal circuitry will ensure a HIGH, stable output state for open inputs.
- 2. Terminated Input. If the driver is disconnected (cable unplugged), or if the driver is in a TRI-STATE or power-off condition, the receiver output will again be in a HIGH state, even with the end of cable 100Ω termination resistor across the input pins. The unplugged cable can become a floating antenna which can pick up noise. If the cable picks up more than 10mV of differential noise, the receiver may see the noise as a valid signal and switch. To insure that any noise is seen as common-mode and not differential, a balanced interconnect should be used. Twisted pair cable will offer better balance than flat ribbon cable.
- 3. **Shorted Inputs.** If a fault condition occurs that shorts the receiver inputs together, thus resulting in a 0V differential input voltage, the receiver output will remain in a HIGH state. Shorted input fail-safe is not supported across the common-mode range of the device (GND to 2.4V). It is only supported with inputs shorted and no external common-mode voltage applied.

External lower value pull up and pull down resistors (for a stronger bias) may be used to boost fail-safe in the presence of higher noise levels. The pull up and pull down resistors should be in the  $5k\Omega$  to  $15k\Omega$  range to minimize loading and waveform distortion to the driver. The common-mode bias point should be set to approximately 1.2V (less than 1.75V) to be compatible with the internal circuitry.

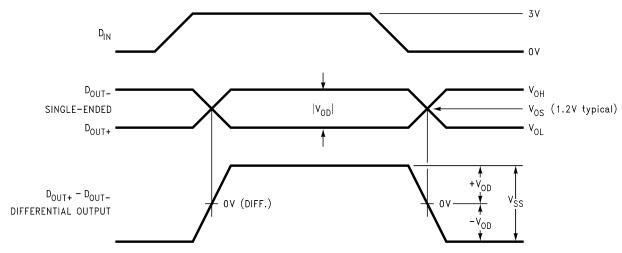


Figure 7. Driver Output Levels

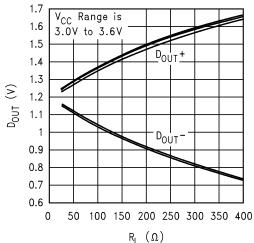
# **Pin Descriptions**

Pin No.	Name	Description
1, 7, 9, 15	D <sub>I</sub>	Driver input pin, TTL/CMOS compatible
2, 6, 10, 14	D <sub>O</sub> +	Non-inverting driver output pin, LVDS levels
3, 5, 11, 13	D <sub>O</sub> -	Inverting driver output pin, LVDS levels
4	En	Active high enable pin, OR-ed with En*
12	En*	Active low enable pin, OR-ed with En
16	$V_{CC}$	Power supply pin, +3.3V ± 0.3V
8	Gnd	Ground pin

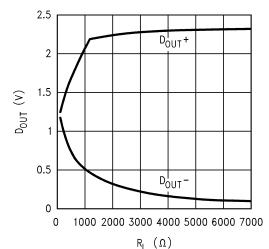
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# **Typical Performance Curves**



 $\begin{array}{c} \mathsf{R}_{\mathsf{L}} \ (\Omega) \\ \text{Figure 8. Typical DS90LV031, T}_{\mathsf{A}} = 25^{\circ}\mathsf{C} \\ \mathsf{D}_{\mathsf{O}} \ (\mathsf{single ended}) \ \mathsf{vs} \ \mathsf{R}_{\mathsf{L}} \end{array}$ 



 $\begin{array}{c} \text{R}_{L} \ (\Omega) \\ \text{Figure 9. Typical DS90LV031, D}_{0} \ \text{vs R}_{L}, \\ \text{V}_{CC} = 3.3 \text{V, T}_{A} = 25 ^{\circ} \text{C} \end{array}$ 

# SNLS204A - NOVEMBER 2011 - REVISED APRIL 2013



# **REVISION HISTORY**

Changes from Original (April 2013) to Revision A						
•	Changed layout of National Data Sheet to TI format					

www.ti.com 15-Aug-2023

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9865101QFA	ACTIVE	CFP	NAD	16	19	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	DS90LV031AW -QML Q 5962-98651 01QFA ACO 01QFA >T	Samples
DS90LV031AW-QML	ACTIVE	CFP	NAD	16	19	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	DS90LV031AW -QML Q 5962-98651 01QFA ACO 01QFA >T	Samples
DS90LV031AWGMLS	ACTIVE	CFP	NAC	16	88	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	DS90LV031AWG MLS ACO MLS >T	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

# **PACKAGE OPTION ADDENDUM**

www.ti.com 15-Aug-2023

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF DS90LV031AQML, DS90LV031AQML-SP:

Military: DS90LV031AQML

Space : DS90LV031AQML-SP

NOTE: Qualified Version Definitions:

- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 1-Aug-2023

# **TUBE**

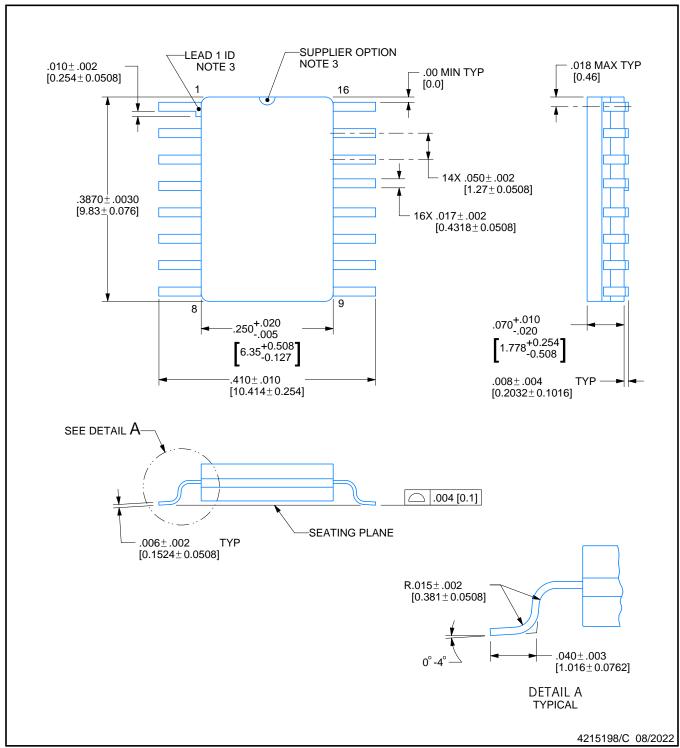


# \*All dimensions are nominal

	Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
ĺ	5962-9865101QFA	NAD	CFP	16	19	502	23	9398	9.78
ĺ	DS90LV031AW-QML	NAD	CFP	16	19	502	23	9398	9.78



CERAMIC FLATPACK

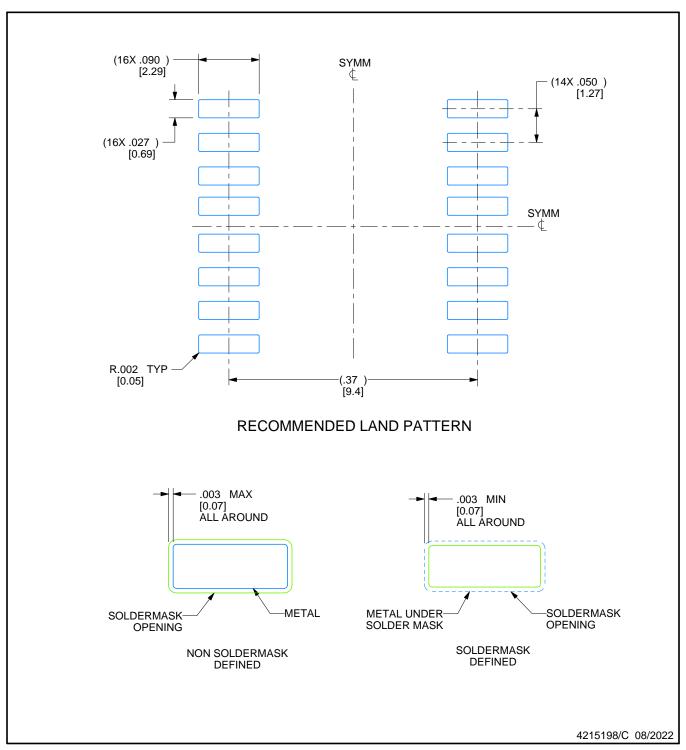


# NOTES:

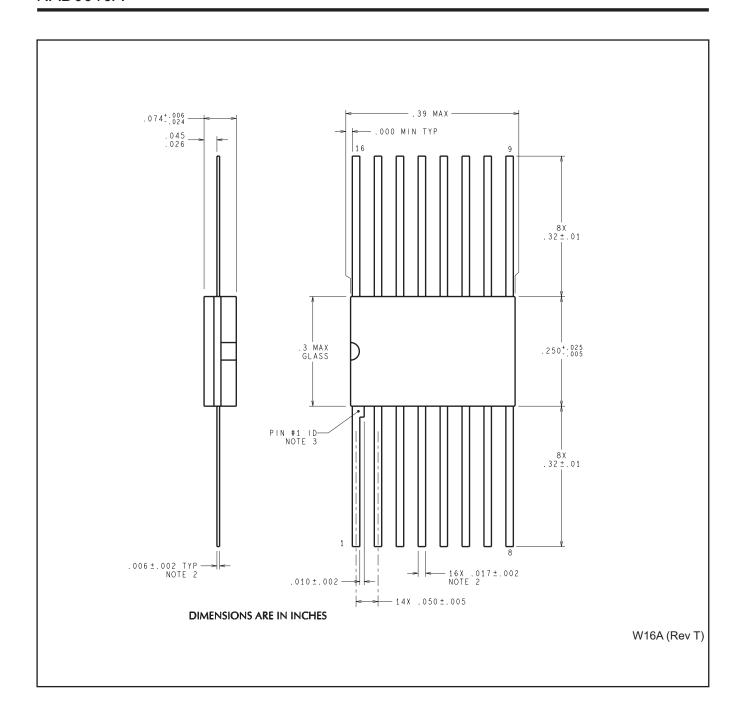
- 1. Controlling dimension is Inch. Values in [] are milimeters. Dimensions in () for reference only.
  2. For solder thickness and composition, see the "Lead Finish Composition/Thickness" link in the packaging section of the Texas Instruments website
- 3. Lead 1 identification shall be:
  - a) A notch or other mark within this area
  - b) A tab on lead 1, either side
- 4. No JEDEC registration as of December 2021



CERAMIC FLATPACK



		RF\/IS	SIONS				
REV	DESCRIPTION	vic	2.3.10	E.C.N.	DATE	BY/AP	P'D
A B C	RELEASE TO DOCUMENT CONTROL  NO CHANGE TO DRAWING; REVISION FOR YODA RELEASE;  .387± .003 WAS .39000± .00012;			2197879 2198832 2200917	12/30/2021 02/15/2022 08/08/2022	TINA TRAN / A  K. SINCE D. CHIN / K. S	ANIS FAUZI RBOX
		SCALE	SIZE <b>A</b>		421519	98	REV PAGE 4 OF 4





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